DNAフェルミ準位近傍の電子状態計測

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Characterization of DNA by Resonant Photoemission Spectroscopy

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Introduction



A candidate for future molecular devices as wire



For DNA, two antithetical mechanisms have been proposed.

(1) Molecular band conduction (delocalized)

(2) Sequential hopping between **localized** bases

The experimental characterization of electronic structures near the Fermi level has been desired to clarify these conduction mechanisms.

Resonant excitation process



Auger electron component





RPES near Fermi level





- M, N, N, Auger 34 34.4 PHOTON ENERGY (eV)

K. Ueda et al., Phys. Rev. A 54, 490 (1996).

Conclusion

Base-molecule-specific electronic structures near the Fermi level of DNA

- Excited electrons into the π^* state affect the Auger transitions
- Finite lifetime ($\geq 10^{-14}$ s) of the π^* state electrons
- Electrons in the π^* state are localized.

Charge Hopping for Conduction (Model 2)

H.S. Kato, M. Furukawa, M. Kawai, M. Taniguchi, T. Kawai, T. Hatsui, and N. Kosugi, Phys. Rev. Lett. 93 (2004) 086403

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Photoemission & X-ray Absorption

Characterization of Iodine-doped DNA

Introduction



Raman Spectroscopy & DFT calculations





Raman shift / cm-

Radical cation formation

Guanine

Cytosine



Conclusion

Elucidation of conductivity enhancement at iodine-doped DNA

- Radical cation formation at Guanine bases

- Appearance of new electronic states in the intrinsic band gap



Formation of the Small Polaron (Characteristics of conductive polymers)

M. Furukawa, H.S. Kato, M. Taniguchi, T. Kawai, T. Hatsui, N. Kosugi, T. Yoshida, M. Aida and M. Kawai, Phys. Rev. B 75 (2007) 045119

New electronic states in the intrinsic band gap